

70T651S10BFI8

70T651S10BFI8 Information

4		70T651S10BFI8 IDT, Integrated Device Technology Inc Integrated Circuits (ICs) Memory IC SRAM 9MBIT 10NS 208CABGA 208-LFBGA For the pricing/inventory/lead time, please contact	
	For Reference Only	us Website: https://www.heisener.com E-mail: salesdent@heisener.com	Request a Quote

E-mail: salesdept@heisener.com

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



70T651S10BFI8 Specifications

Manufacturer Part Number	70T651S10BFI8
Manufacturer	IDT, Integrated Device Technology Inc
Category	Integrated Circuits (ICs)
	Memory
Package	208-LFBGA
Series	-
Memory Type	Volatile
Memory Format	SRAM
Technology	SRAM - Dual Port, Asynchronous
Memory Size	9Mb (256K x 36)
Memory Interface	Parallel
Clock Frequency	-
Write Cycle Time - Word, Page	10ns
Access Time	10ns
Voltage - Supply	2.4 V ~ 2.6 V
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	208-LFBGA
Supplier Device Package	208-CABGA (15x15)
	Report errors?

70T651S10BFI8 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE UARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

70T651S10BFI8 Payment Methods



If you have any question about 70T651S10BFI8, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com